DH257 Hall-effect sensor is a temperature stable, stress-resistant, Low Tolerance of Sensitivity micro-power switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

DH257 is special made for low operation voltage, 2.5V, to active the chip which is includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, CMOS output driver. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries. This device requires the presence of unipolar magnetic fields for operation.

The package type is in a Halogen Free version has been verified by third party Lab.

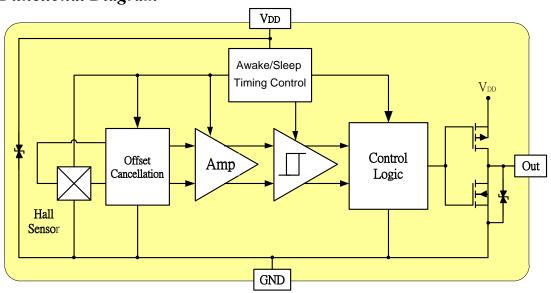
### Features and Benefits

- CMOS Hall Effect IC
- Totem-pole output
- Omni polar output switch
- Micro-power consumption
- Low working voltage at 2.5V
- High ESD protection
- RoHS compliant 2011/65/EU and Halogen Free

### **Applications**

- Solid state switch
- Handheld Wireless Handset Awake Switch (Flip Cell/PHS Phone/Note Book/Flip Video Set)
- Magnet proximity sensor for reed switch replacement in low duty cycle applications
- Water Meter
- PDA
- PDVD
- NB
- Pad PC

### Functional Diagram



Note: Static sensitive device; please observe ESD precautions. Reverse  $V_{DD}$  protection is not included. For reverse voltage protection, a  $100\Omega$  resistor in series with  $V_{DD}$  is recommended.

DH257, HBM  $> \pm 4KV$  which is verified by third party lab.

Absolute Maximum Ratings At(Ta=25 °C)

Characterist	Values	Unit	
Supply voltage,(VDD)		6	V
Output Voltage,(Vout)	6	V	
Reverse Voltage, (VDD) (VOUT)		-0.3	V
Magnetic flux density		Unlimited	Gauss
Output current,(Iour)		1	mA
Operating temperature range, (Ta)		-40 to +85	°C
Storage temperature range, ( <i>Ts</i> )		-65 to +150	$^{\circ}$
Maximum Junction Temp,( <i>Tj</i> )		150	°C
Thermal Resistance	$(\theta_{JA})$ ST/SQ/UA	310/540/206	°C/W
	$(\theta_{IC})$ ST/SQ/UA	223/390/148	°C/W
Package Power Dissipation, $(P_D)$ ST/SQ/UA		400/230 /606	mW

**Note:** Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

# **Electrical Specifications**

DC Operating Parameters : Ta=25°C,  $V_{DD}=2.0V$ 

Parameters	<b>Test Conditions</b>	Min	Тур	Max	Units
Supply Voltage,(VDD)	Operating	2.5		5.5	Volts
Supply Current,(IDD)	Awake State		1.4	3	mA
	Sleep State		3.5	7	μΑ
	Average		5	10	μΑ
Output Leakage Current,(Ioff)	Output off			1	uA
Output High Voltage,(VOH)	Iout=0.5mA(Source)	V <sub>DD</sub> -0.2			V
Output Low Voltage,(Vol)	Iout=0.5mA(Sink)			0.2	V
Awake mode time,( <i>Taw</i> )	Operating		40	80	uS
Sleep mode time,(TsL)	Operating		40	80	mS
Duty Cycle,(D,C)			0.1		%
Electro-Static Discharge	НВМ	4			KV

## DH257E ST/SQ/UA Magnetic Specifications

DC Operating Parameters : Ta=25 °C,  $V_{DD}=2.0V$ 

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>Operating Point</b>	$\mathrm{B}_{\mathrm{OP}}$	S pole to branded side, B > BOP, Vout On		30	55	Gauss
Release Point	$\mathrm{B}_{\mathrm{RP}}$	S pole to branded side, B < BRP, Vout Off	10	20	45	Gauss
Hysteresis	$\mathrm{B}_{\mathrm{HY}}$	BOPx - BRPx		10		Gauss

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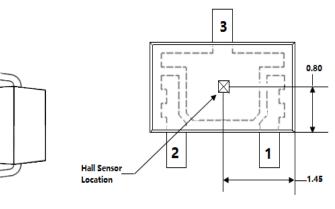
### Sensor Location, package dimension and marking

### ST Package (TSOT-23)

# 

### **Hall Plate Chip Location**





### **NOTES:**

1. PINOUT (See Top View at left:)

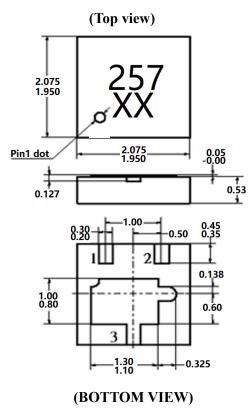
Pin 1 VDD

Pin 2 Output

Pin 3 GND

2. Controlling dimension: mm;

### SQ Package (QFN2020-3)



### **NOTES:**

1. PINOUT (See Top View at

left)

Pin 1 VDD

Pin 2 Output

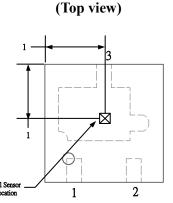
Pin 3 GND

2. Controlling dimension: mm;

3. Chip rubbing will be 10mil maximum;

4. Chip must be in PKG. center.

Hall Plate Chip Location



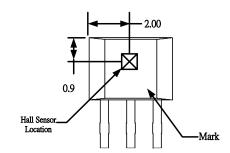
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### **UA Package (TO-92S)**

# 45.00° 0.75 1.62 1.42 3.90 2.90 XXX 1.60 1.50 1.50

0.36

### **Hall Chip location**



### **NOTES:**

- 1).Controlling dimension: mm
- 2).Leads must be free of flash and plating voids
- 3).Do not bend leads within 1 mm of lead to package interface.
- 4).PINOUT:

Pin 1 VDD

Pin 2 GND

Pin 3 Output

# **Output Pin Assignment**

(Top view)

